

Fig. 3

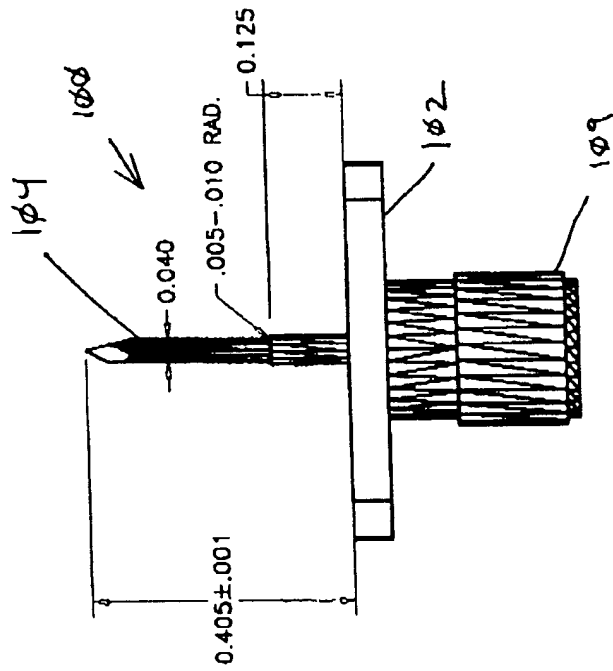


Fig. 4(a)

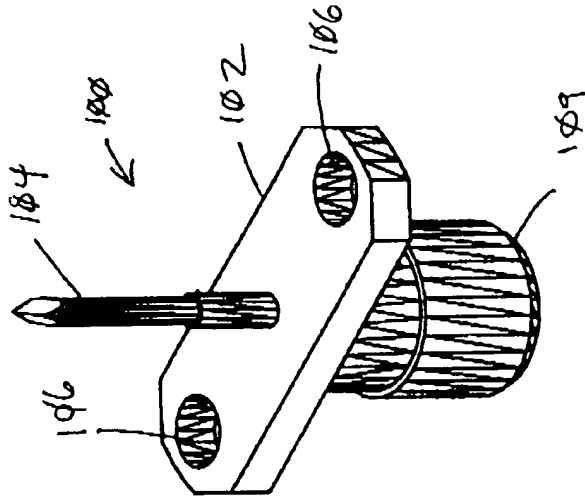


Fig. 4(b)

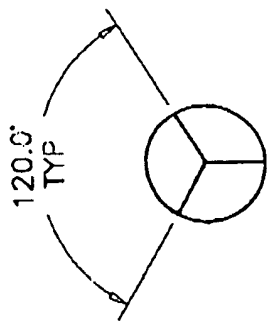


Fig. 4(e)

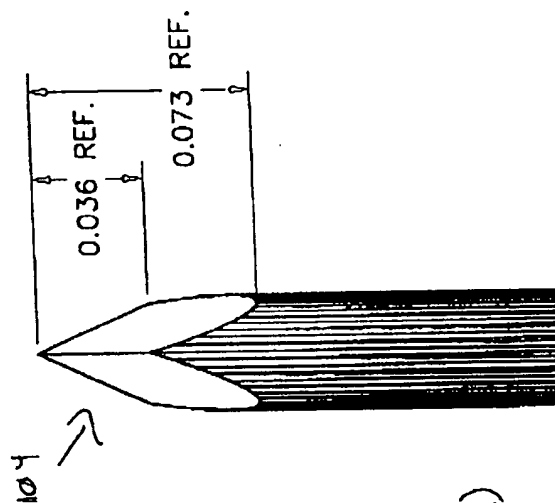


Fig. 4(a)

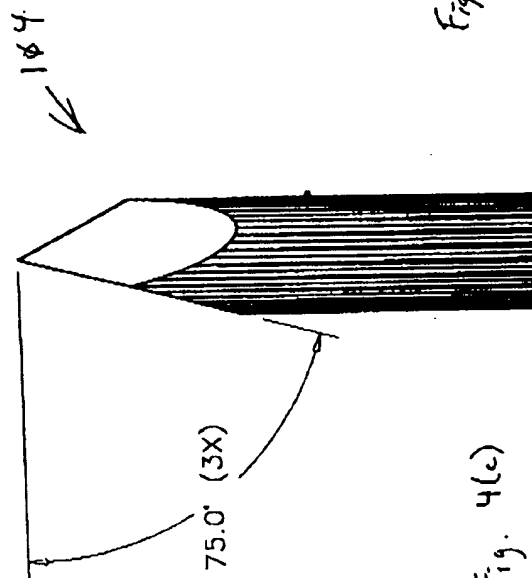


Fig. 4(c)

FIG. 5(a) is a perspective view of a corner of a structure 110, showing a top surface 112, a side surface 114, and a bottom surface 116. The corner is defined by a vertical edge 118 and a horizontal edge 120. The top surface 112 is inclined at an angle of 38.6° relative to the horizontal edge 120. The side surface 114 is inclined at an angle of 53.1° relative to the vertical edge 118. The bottom surface 116 is inclined at an angle of 0.020° relative to the horizontal edge 120. The vertical edge 118 has a height of 0.040. The horizontal edge 120 has a width of 0.040.

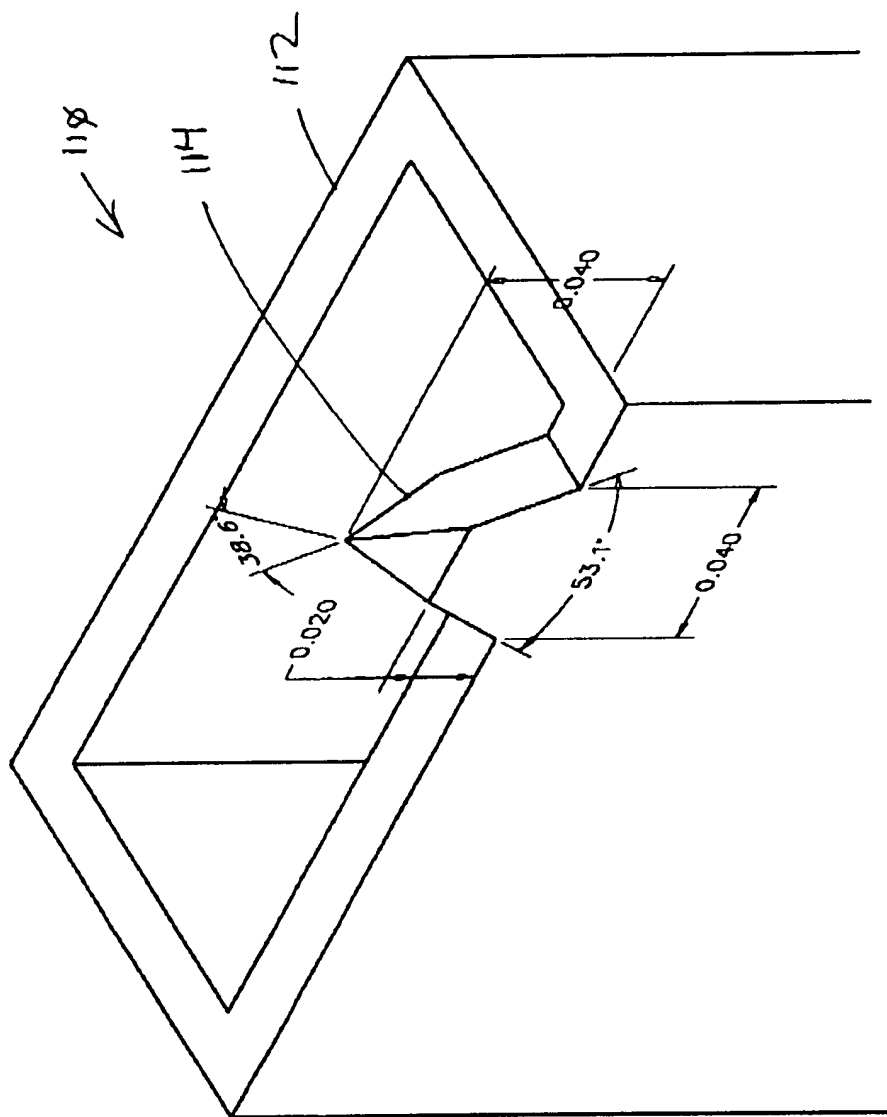
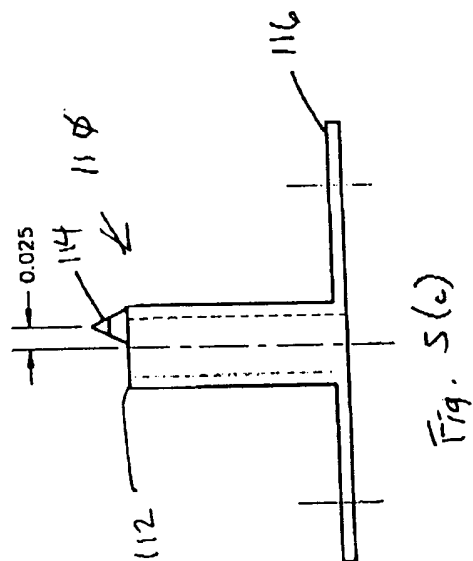
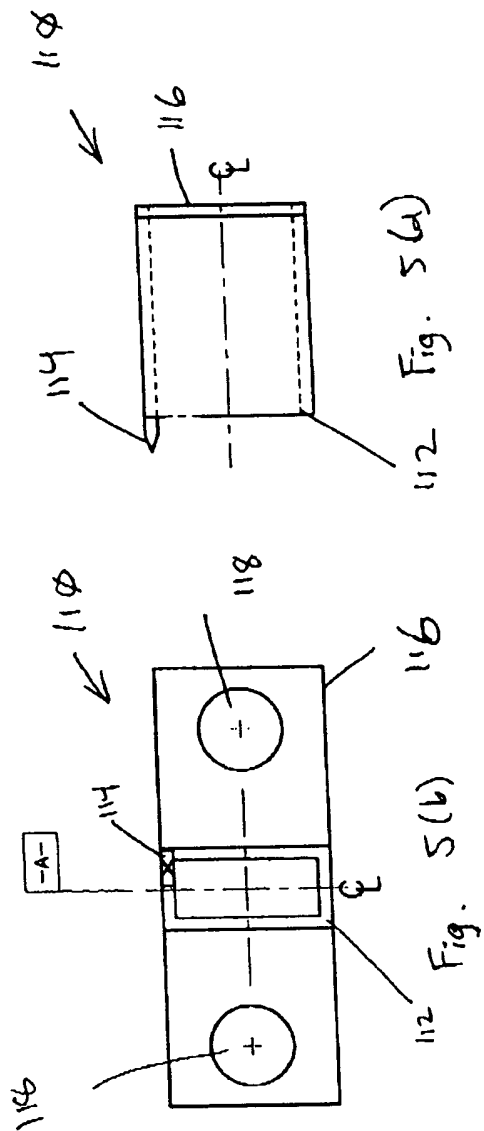
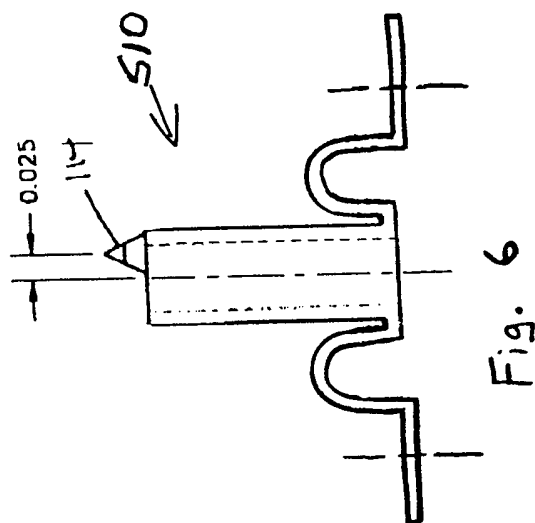


Fig. 5(a)







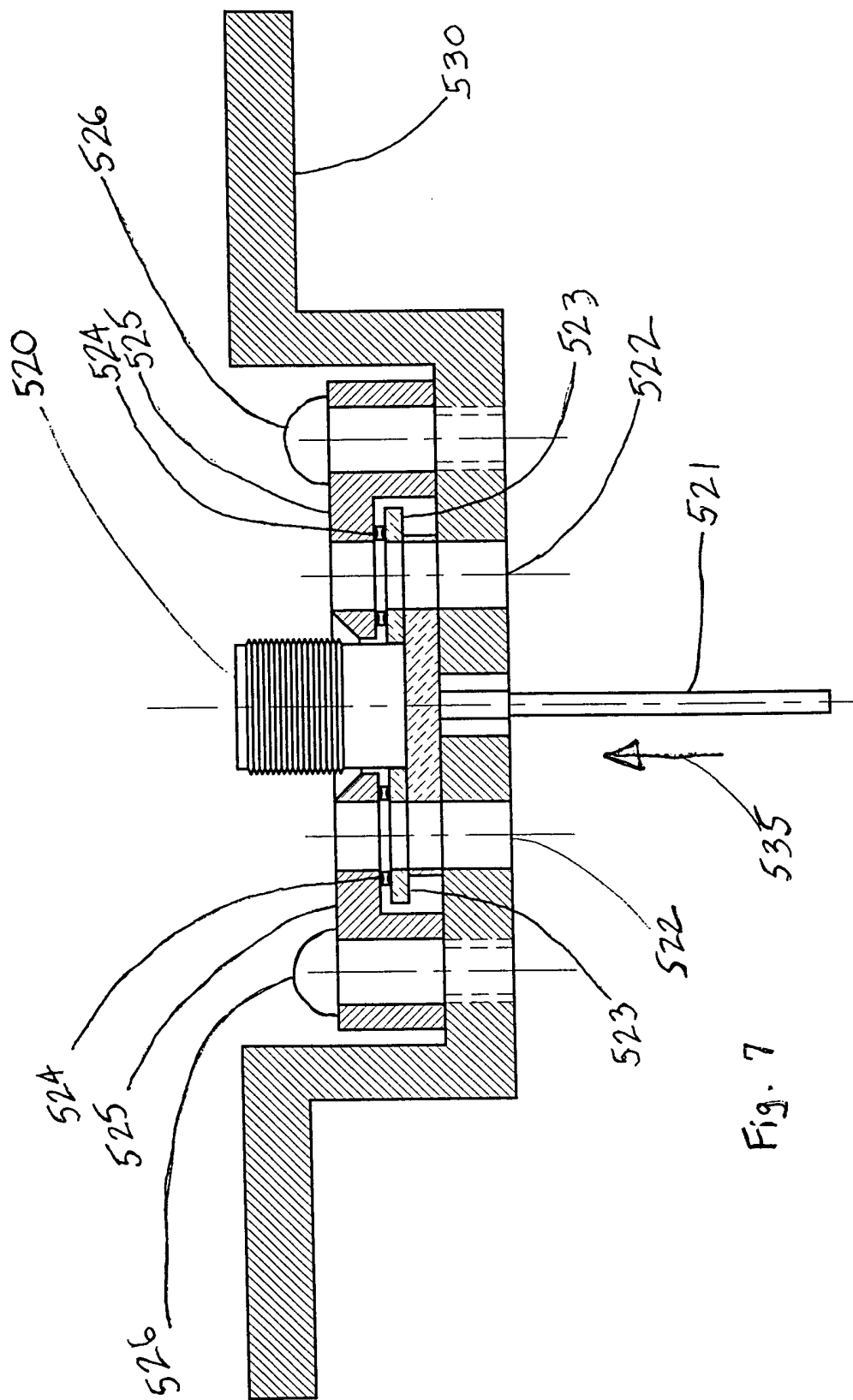


Fig. 7

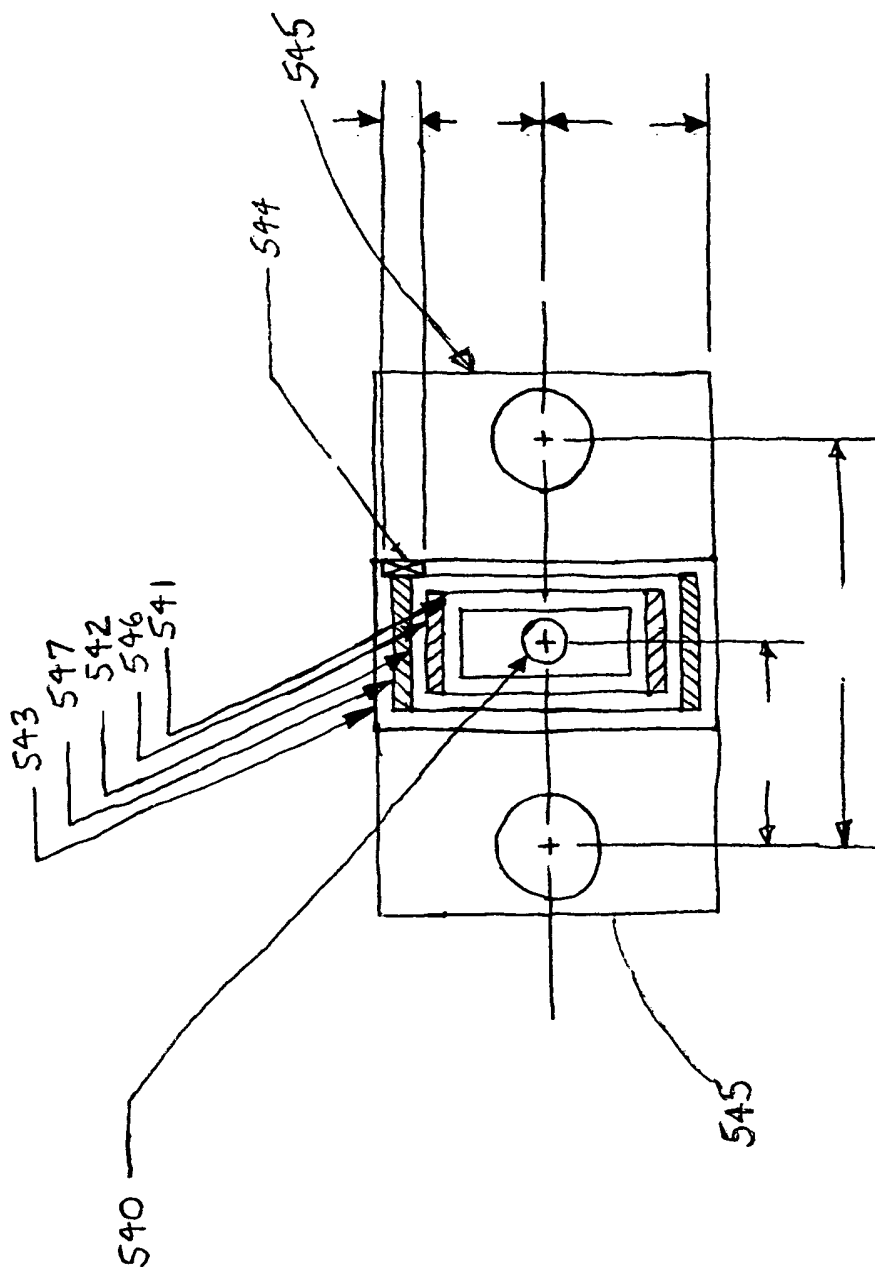


Fig. 8

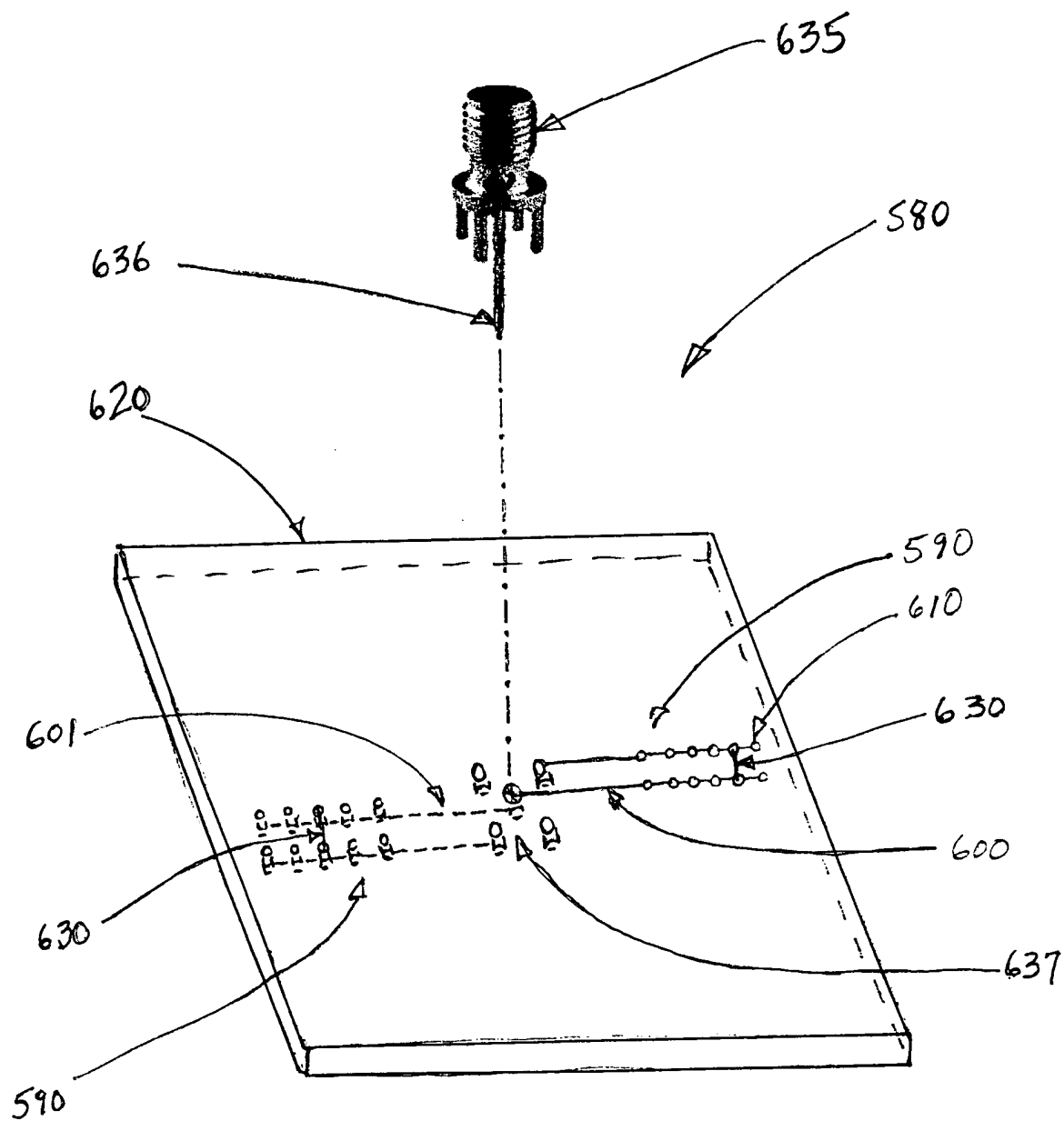


Fig. 9

FIG. 10 is a perspective view of the device of FIG. 9, showing the device in a closed position. The device is shown in a perspective view, and the components are labeled with reference numerals. The device is shown in a perspective view, and the components are labeled with reference numerals.

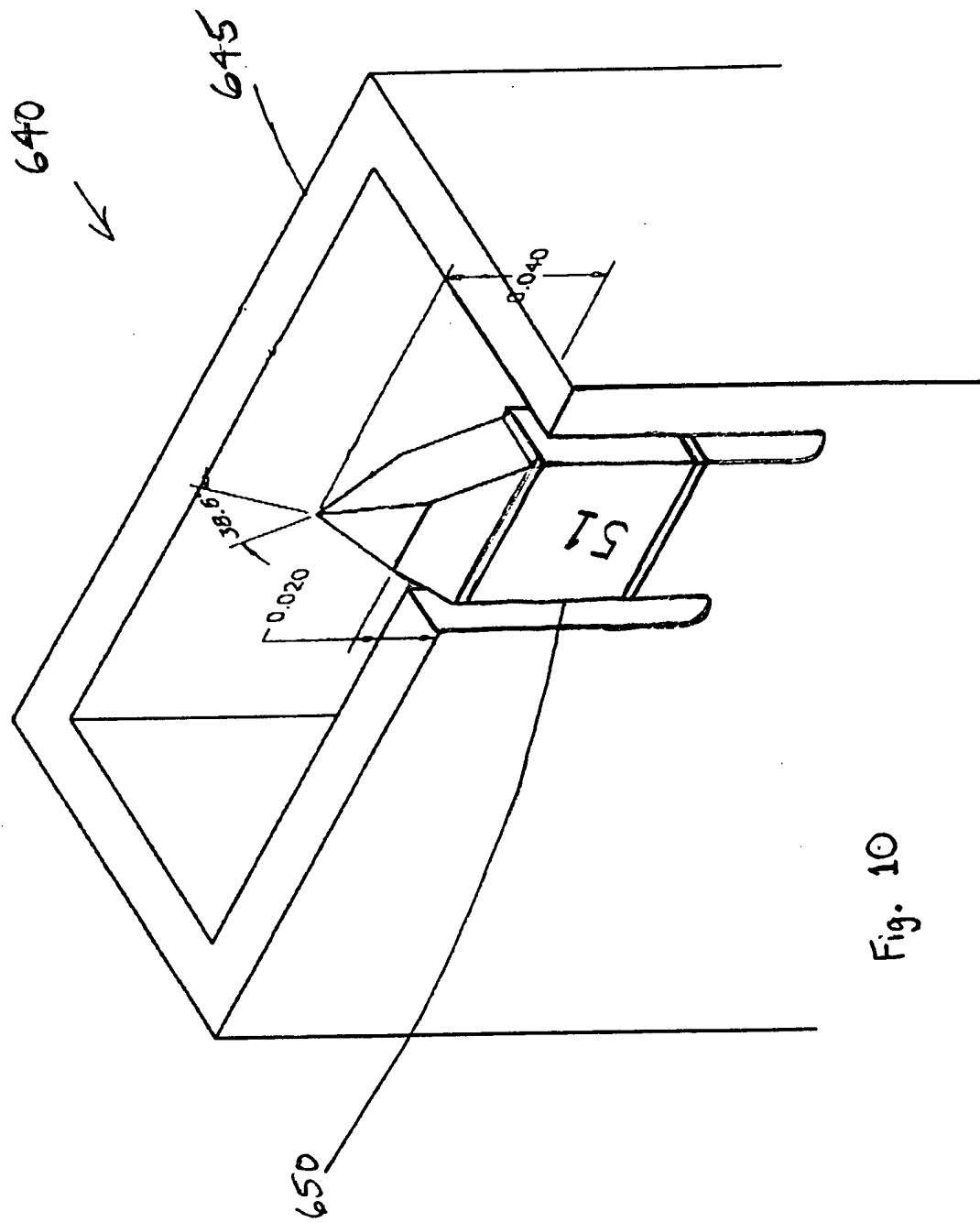


Fig. 10

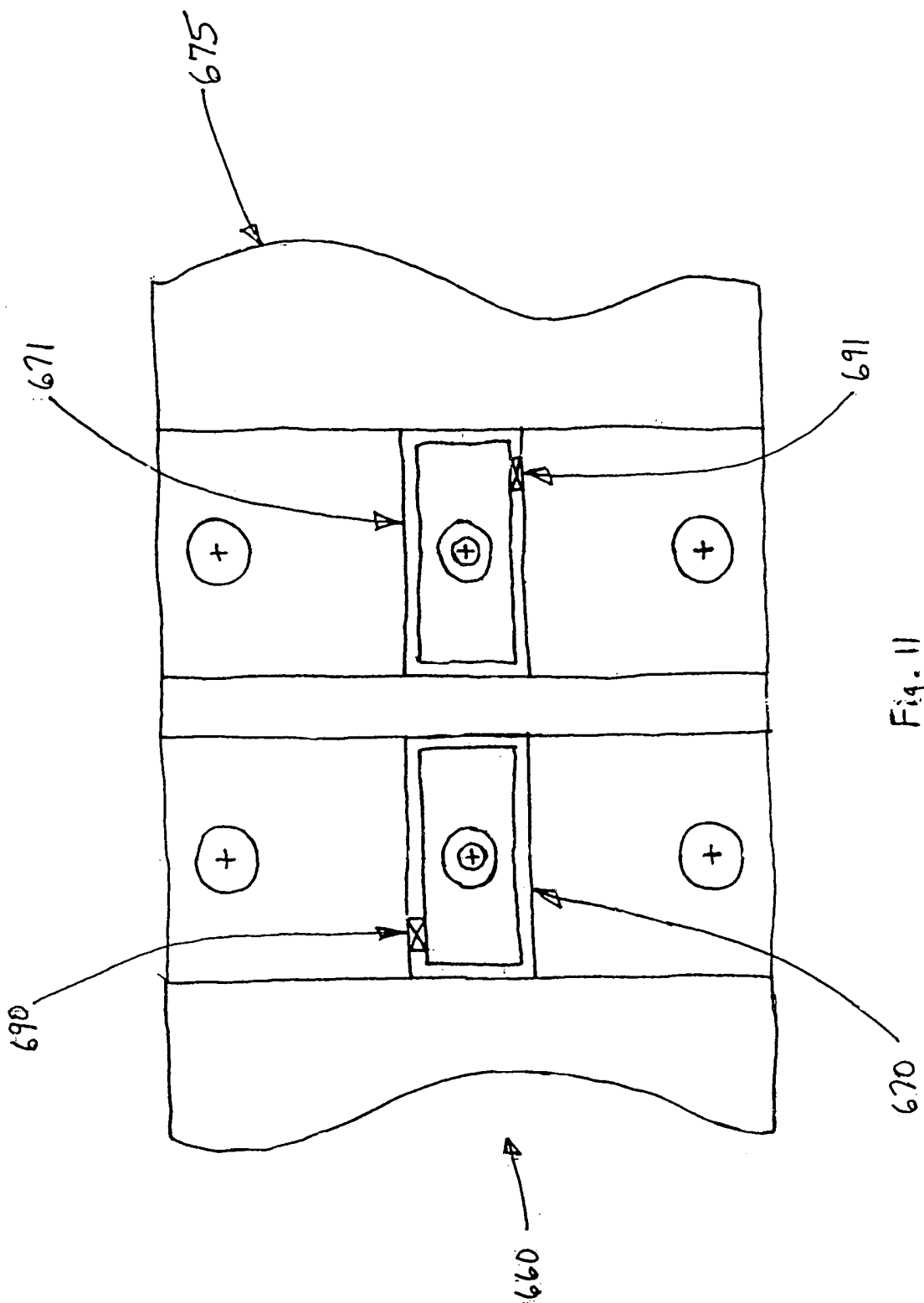


Fig. 11

FIG. 12 is a schematic diagram of a device 700, which is a cross-sectional view of a device 700. The device 700 includes a substrate 710, a first layer 713, a second layer 714, a third layer 715, and a fourth layer 716. The first layer 713 is a conductive layer, the second layer 714 is a dielectric layer, the third layer 715 is a conductive layer, and the fourth layer 716 is a dielectric layer. The device 700 is a cross-sectional view of a device 700, which is a cross-sectional view of a device 700.

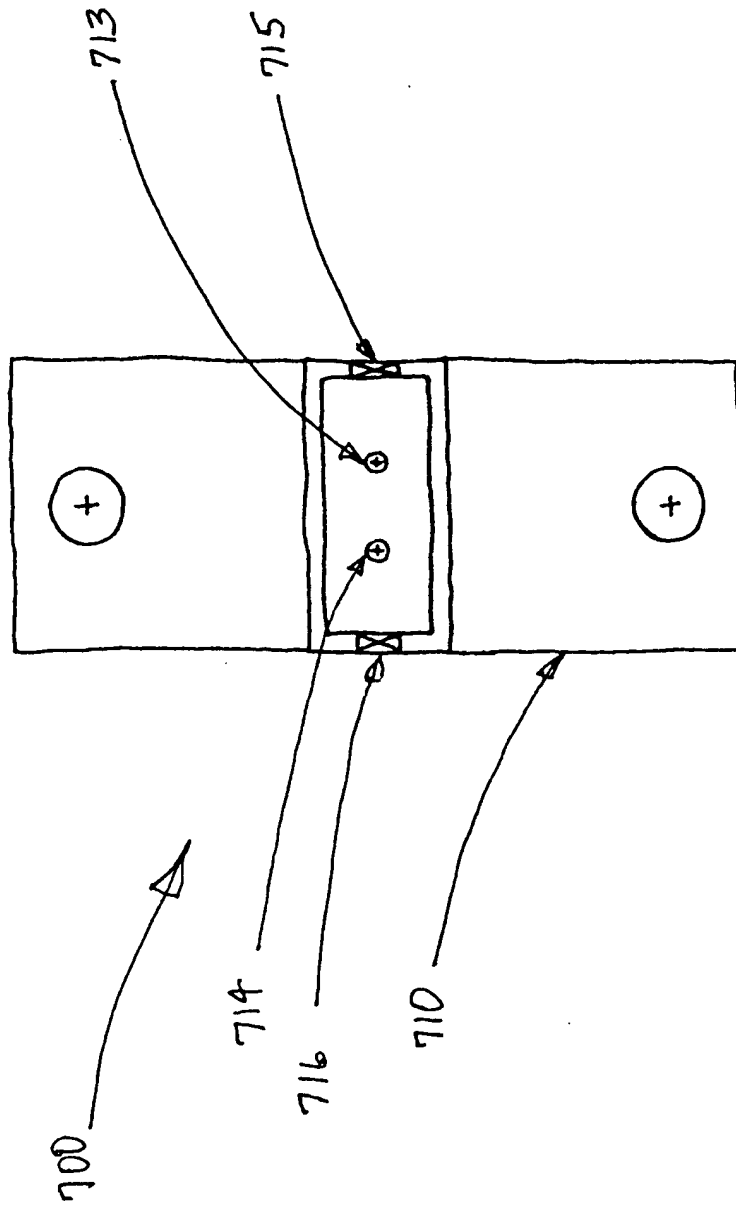


Fig. 12

FIG. 13

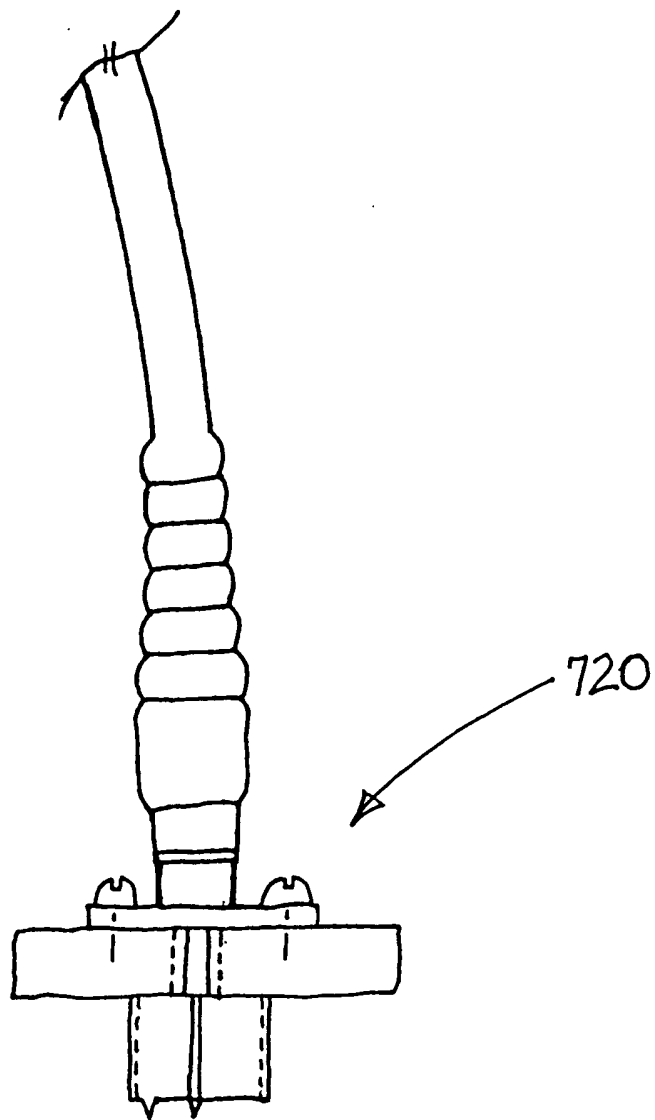


Fig. 13